There are many ways to generate ultrafast laser operations. One can use real saturable absorbers, such as semiconductor saturable absorber mirror (SEASM) [SESAM mode-locked red praseodymium laser] or low-dimensional material-based saturable absorbers such as graphene [] and blablabla [], and solid-state laser media []. One can also exploit artificial saturable absorbers. The two most prominent artificial saturable absorber mode locking techniques are called Kerr-Lens Mode Locking (KLM) [1][2][3][4][5][6][7] early[8][9][10] and Additive Pulse Mode Locking (APM) [].

By virtue of its vast variety of robust emission lines ranging from visible to near infrared spectral range, trivalent praseodymium (Pr3+) ions have been identified as one of the most potential candidates for efficient visible lasers.

In recent years, with the development of blue laser diodes (LDs), which are both compact and easily available, diode-pumped all solid-state Pr3+-doped material visible lasers are gradually attracting more and more attention.

Pr3 -doped crystal visible lasers have achieved tremendous

progress in continuous-wave (cw) operations, and high efficiency

cw Pr3 ion visible lasers have been widely studied with

the slope efficiencies close to the theoretical maximum at the

wavelengths of 522 and 639 nm [5]. In pulse laser experiments,

LD-pumped Q-switched Pr3 ion visible lasers with kilohertz

repetition rates and nanosecond pulse widths have been reported [6,7].

Pr:YLF

The first mode-locked Pr3+:YLiF4 visible lasers at 607 and 640 nm utilizing the Kerr-lensing effect and initiated by saturable absorbers were realized in 1995 by introducing argon-ion lasers as the pump source. [Kerr-lens mode-locked visible transitions of a Pr:YLF laser]. The first self-staring Kerr-lens mode locked laser at 607 nm with pulses width of 15 ps was reported in 1996, which was also pumped by an argon-ion laser [Self-starting Kerr-lens mode-locked femtosecond Cr4+:YAG and picosecond Pr3+:YLF solid-state lasers]. In 2014, pumped by an intra-cavity frequency-doubled Optically Pumped InGaAs Semiconductor Laser (2ω-OPSL), the first semiconductor saturable absorber mirror (SESAM) mode-locked praseodymium solid-state laser at 640 nm was obtained by Gaponenko et al, with pulses duration of ∼18 ps. [SESAM mode-locked red praseodymium laser]. Due to the narrow gain bandwidth of the transition (3P0→3F2) in the Pr3+:YLF, generating mode-locked sub-picosecond pulses is challenging. The maximum averaged output power reached 16 mW at an incident pump power of 3.75 W.

In the past one year, the wavelength of self-mode-locked visible pulsed lasers extent to the spectral range of green and deep red for the first time [Laser-diode pumped self-mode-locked praseodymium visible lasers with multi-gigahertz repetition rate]. The system was pumped by laser-diode and the repetition rates were multi-gigahertz (GHz). The maximum output power reached 612 mW with the slope efficiency of 46.9% at 639 nm. Following closely, still by introducing a SESAM, but pumped by InGaN laser-diode, which is different from Gaponenko et al, mode-locking operation at the wavelength of 640 nm was attained. [Pr3+:YLF mode-locked laser at 640 nm directly pumped by InGaN-diode lasers]. a maximum averaged output power of 65 mW was obtained at absorbed pump power of 3.8 W, with a pulse width of 45 ps (FWHM) at a pulse repetition rate of 108 MHz.

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